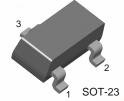


## **FJV4104R**

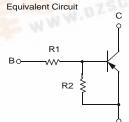
### Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R<sub>1</sub>=47K $\Omega$ , R<sub>2</sub>=47K $\Omega$ )
- Complement to FJV3104R



1. Base 2. Emitter 3. Collector





## PNP Epitaxial Silicon Transistor

## Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	-50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-50	V
/ <sub>EBO</sub>	Emitter-Base Voltage	-10	V
С	Collector Current	-100	mA
c c	Collector Power Dissipation	200	mW
Γ <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

### Electrical Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = -10\mu A, I_{E} = 0$	-50			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = -100 \mu A, I_B = 0$	-50	da-		V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -40V, I <sub>E</sub> =0			-0.1	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE} = -5V$ , $I_{C} = -5mA$	68	44.44		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$			-0.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = -10V, I <sub>C</sub> =-5mA		200		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0 f=1.0MHz		5.5		pF
V <sub>I</sub> (off)	Input Off Voltage	$V_{CE}$ = -5V, $I_{C}$ = -100 $\mu$ A	-0.5			V
V <sub>I</sub> (on)	Input On Voltage	$V_{CE}$ = -0.3V, $I_{C}$ = -2mA			-3	V
R <sub>1</sub>	Input Resistor		32	47	62	ΚΩ
R <sub>1</sub> /R <sub>2</sub>	Resistor Ratio		0.9	1	1.1	

## **Typical Characteristics**

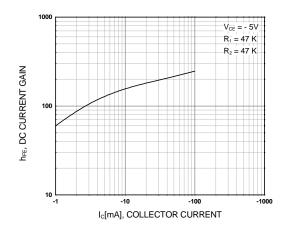


Figure 1. DC current Gain

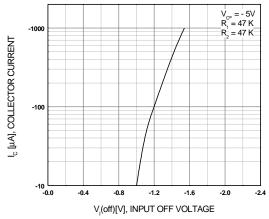


Figure 3. Input Off Voltage

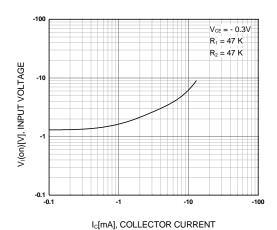


Figure 2. Input On Voltage

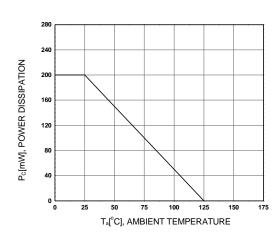
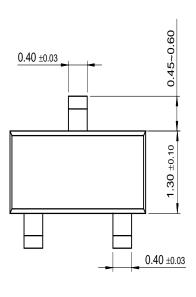


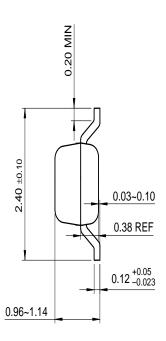
Figure 4. Power Derating

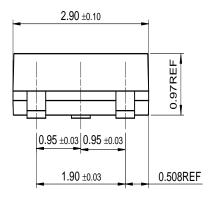
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# **Package Dimensions**

# SOT-23







Dimensions in Millimeters

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EcoSPARK™	GTO™ .	MSX™	QT Optoelectronics™	TinyLogic™
$E^2CMOS^{TM}$	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
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